

NPN Epitaxial Silicon Transistor

KSC3265

Low Frequency Power Amplifier

• Complement to KSA1298

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted.)

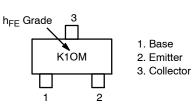
| Symbol | Parameter | Ratings | Unit |
|------------------|-----------------------------|-----------|------|
| V _{CBO} | Collector-Base Voltage | 30 | V |
| V _{CEO} | Collector-Emitter Voltage | 25 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current | 800 | mA |
| lΒ | Base Current | 160 | mA |
| PC | Collector Power Dissipation | 200 | mW |
| TJ | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



SOT-23 CASE 318

MARKING DIAGRAM



K1O = Specific Device Code M = Date Code

ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|---------------------|-----------------------|
| KSC3265YMTF | SOT-23 (Pb-Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|--------------------------------------|--|-----------|--------|----------|------|
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C = 10 mA, I _B = 0 | 25 | - | - | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E = 1 mA, I _C = 0 | 5 | - | - | V |
| I _{CBO} | Collector Cut-off Current | V _{CB} = 30 V, I _E = 0 | - | - | 100 | nA |
| I _{EBO} | Emitter Cut-off Current | V _{BE} = 5 V, I _C = 0 | - | - | 100 | nA |
| h _{FE1} | DC Current Gain | $V_{CE} = 1 \text{ V, } I_{C} = 100 \text{ mA}$ $V_{CE} = 6 \text{ V, } I_{C} = 800 \text{ mA}$ | 100 40 | - - | 320 - | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = 500 mA, I _B = 20 mA | - | - | 0.4 | V |
| V _{BE} (on) | Base-Emitter On Voltage | V _{CE} = 1 V, I _C = 10 mA | 0.5 | - | 0.8 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} = 5 V, I _C = 10 mA | _ | 120 | _ | MHz |
| C _{ob} | Output Capacitance | V _{CB} = 10 V, I _E = 0, f = 1 MHz | _ | 13 | _ | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

h_{FE1} Classification

| Classification | 0 | Υ | |
|------------------|-----------|-----------|--|
| h _{FE1} | 100 ~ 200 | 160 ~ 320 | |

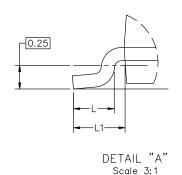




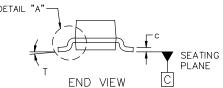
SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

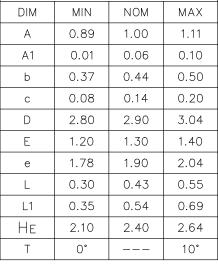
DATE 14 AUG 2024





DETAIL "A"





MILLIMETERS

NOTES:

- DIMENSIONING AND TOLERANCING 1. PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS:
- MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*

SIDE VIEW

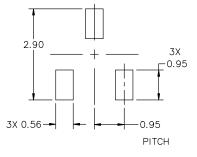


XXX = Specific Device Code

= Date Code

= Pb-Free Package

^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 14 AUG 2024

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | | | |
|---|---|---------------|---|---|
| STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE | STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE | 2. CATHODE 2. | 2: STYLE 13: CATHODE PIN 1. SOURCE CATHODE 2. DRAIN ANODE 3. GATE | STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE |
| STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE | STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE | 2. ANODE 2. | 3: STYLE 19: NO CONNECTION PIN 1. CATHODE CATHODE 2. ANODE ANODE 3. CATHODE-ANODE | STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE |
| STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN | STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT | | | STYLE 26: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION |
| STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE | | | |

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